

### FEATURES

**Bandwidth:** >400 MHz

**Low insertion loss and on resistance:** 2.2  $\Omega$  typical

**On resistance flatness:** 0.3  $\Omega$  typical

**Single 3 V/5 V supply operation**

**Very low distortion:** <0.3%

**Low quiescent supply current:** 1 nA typical

**Fast switching times**

$t_{ON} = 6$  ns

$t_{OFF} = 3$  ns

**TTL-/CMOS-compatible**

**Pb-free packages**

**16-lead QSSOP**

**16-lead 3 mm  $\times$  3 mm body LFCSP**

### FUNCTIONAL BLOCK DIAGRAM

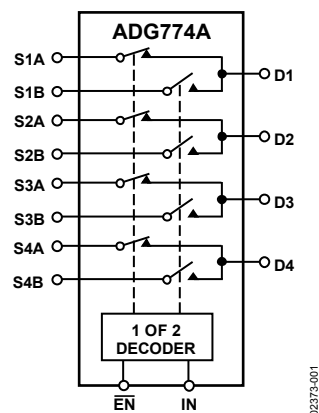


Figure 1.

### GENERAL DESCRIPTION

The ADG774A is a monolithic CMOS device comprising four 2:1 multiplexer/demultiplexers with high impedance outputs. The CMOS process provides low power dissipation yet offers high switching speed and low on resistance. The on resistance variation is typically less than 0.5  $\Omega$  over the input signal range.

The bandwidth of the ADG774A is typically 400 MHz and this, coupled with low distortion (typically 0.3%), makes the part suitable for switching of high speed data signals.

The on resistance profile is very flat over the full analog input range ensuring excellent linearity and low distortion. CMOS construction ensures ultralow power dissipation.

The ADG774A operates from a single 3.3 V/5 V supply and is TTL logic-compatible. The control logic for each switch is shown in the truth table (see Table 5).

These switches conduct equally well in both directions when on. In the off condition, signal levels up to the supplies are blocked. The ADG774A switches exhibit break-before-make switching action.

### PRODUCT HIGHLIGHTS

1. Wide bandwidth data rates of >400 MHz.
2. Ultralow power dissipation.
3. Low leakage over temperature.
4. Break-before-make switching prevents channel shorting when the switches are configured as a multiplexer.
5. Crosstalk is typically -70 dB @ 10 MHz.
6. Off isolation is typically -65 dB @ 10 MHz.
7. Available in compact 3 mm  $\times$  3 mm LFCSP.

#### Rev. B

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REVISION HISTORY

|                                  |           |                                         |   |
|----------------------------------|-----------|-----------------------------------------|---|
| <b>8/06—Rev. A to Rev. B</b>     |           | <b>4/03—Rev. 0 to Rev. A</b>            |   |
| Updated Format.....              | Universal | Changes to TPCs 9–11 .....              | 5 |
| Added LFCSP Model.....           | Universal | Updated Outline Dimensions .....        | 8 |
| Added Lead-Free Models .....     | Universal |                                         |   |
| Changes to Table 3.....          | 5         | <b>7/01—Revision 0: Initial Version</b> |   |
| Updated Outline Dimensions ..... | 13        |                                         |   |
| Changes to Ordering Guide .....  | 13        |                                         |   |

# SPECIFICATIONS

## SINGLE SUPPLY

$V_{DD} = 5\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , all specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.<sup>1</sup>

Table 1.

| Parameter                                                      | B Version |                                      | Unit    | Test Conditions/Comments                                                                              |
|----------------------------------------------------------------|-----------|--------------------------------------|---------|-------------------------------------------------------------------------------------------------------|
|                                                                | 25°C      | T <sub>MIN</sub> to T <sub>MAX</sub> |         |                                                                                                       |
| ANALOG SWITCH                                                  |           |                                      |         |                                                                                                       |
| Analog Signal Range                                            |           | 0 to 2.5                             | V       |                                                                                                       |
| On Resistance, R <sub>ON</sub>                                 | 2.2       |                                      | Ω typ   | V <sub>D</sub> = 0 V to 1 V, I <sub>S</sub> = −10 mA                                                  |
|                                                                | 3.5       | 4                                    | Ω max   |                                                                                                       |
| On Resistance Match Between Channels, ΔR <sub>ON</sub>         | 0.15      |                                      | Ω typ   | V <sub>D</sub> = 0 V to 1 V, I <sub>S</sub> = −10 mA                                                  |
|                                                                |           | 0.5                                  | Ω max   |                                                                                                       |
| On Resistance Flatness, R <sub>FLAT(ON)</sub>                  | 0.3       |                                      | Ω typ   | V <sub>D</sub> = 0 V to 1 V, I <sub>S</sub> = −10 mA                                                  |
|                                                                |           | 0.6                                  | Ω max   |                                                                                                       |
| LEAKAGE CURRENTS                                               |           |                                      |         |                                                                                                       |
| Source Off Leakage, I <sub>S</sub> (OFF)                       | ±0.001    |                                      | nA typ  | V <sub>D</sub> = 3 V/1 V, V <sub>S</sub> = 1 V/3 V, see Figure 17                                     |
|                                                                | ±0.1      | ±0.25                                | nA max  |                                                                                                       |
| Drain Off Leakage, I <sub>D</sub> (OFF)                        | ±0.001    |                                      | nA typ  | V <sub>D</sub> = 3 V/1 V, V <sub>S</sub> = 1 V/3 V, see Figure 17                                     |
|                                                                | ±0.1      | ±0.25                                | nA max  |                                                                                                       |
| Channel On Leakage, I <sub>D</sub> , I <sub>S</sub> (ON)       | ±0.001    |                                      | nA typ  | V <sub>D</sub> = V <sub>S</sub> = 3 V/1 V, see Figure 18                                              |
|                                                                | ±0.1      | ±0.25                                | nA max  |                                                                                                       |
| DIGITAL INPUTS                                                 |           |                                      |         |                                                                                                       |
| Input High Voltage, V <sub>INH</sub>                           |           | 2.4                                  | V min   |                                                                                                       |
| Input Low Voltage, V <sub>INL</sub>                            |           | 0.8                                  | V max   |                                                                                                       |
| Input Current                                                  |           |                                      |         |                                                                                                       |
| I <sub>INL</sub> or I <sub>INH</sub>                           | 0.001     |                                      | μA typ  | V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>                                                |
|                                                                |           | ±0.1                                 | μA max  |                                                                                                       |
| Digital Input Capacitance, C <sub>IN</sub>                     |           | 3                                    | pF typ  |                                                                                                       |
| DYNAMIC CHARACTERISTICS <sup>2</sup>                           |           |                                      |         |                                                                                                       |
| t <sub>ON</sub> , t <sub>ON</sub> ( $\overline{\text{EN}}$ )   |           | 6                                    | ns typ  | C <sub>L</sub> = 35 pF, R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 2 V, see Figure 22                    |
|                                                                |           | 12                                   | ns max  |                                                                                                       |
| t <sub>OFF</sub> , t <sub>OFF</sub> ( $\overline{\text{EN}}$ ) |           | 3                                    | ns typ  | C <sub>L</sub> = 35 pF, R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 2 V, see Figure 22                    |
|                                                                |           | 6                                    | ns max  |                                                                                                       |
| Break-Before-Make Time Delay, t <sub>D</sub>                   |           | 3                                    | ns typ  | C <sub>L</sub> = 35 pF, R <sub>L</sub> = 50 Ω, V <sub>S1</sub> = V <sub>S2</sub> = 2 V, see Figure 23 |
|                                                                |           | 1                                    | ns min  |                                                                                                       |
| Off Isolation                                                  |           | −65                                  | dB typ  | f = 10 MHz, R <sub>L</sub> = 50 Ω, see Figure 20                                                      |
| Channel-to-Channel Crosstalk                                   |           | −70                                  | dB typ  | f = 10 MHz, R <sub>L</sub> = 50 Ω, see Figure 21                                                      |
| Bandwidth −3 dB                                                |           | 400                                  | MHz typ | R <sub>L</sub> = 50 Ω, see Figure 19                                                                  |
| Distortion                                                     |           | 0.3                                  | % typ   | R <sub>L</sub> = 100 Ω                                                                                |
| Charge Injection                                               |           | 6                                    | pC typ  | C <sub>L</sub> = 1 nF, see Figure 24, V <sub>S</sub> = 0 V                                            |
| C <sub>S</sub> (OFF)                                           |           | 5                                    | pF typ  |                                                                                                       |
| C <sub>D</sub> (OFF)                                           |           | 7.5                                  | pF typ  |                                                                                                       |
| C <sub>D</sub> , C <sub>S</sub> (ON)                           |           | 12                                   | pF typ  |                                                                                                       |
| POWER REQUIREMENTS                                             |           |                                      |         |                                                                                                       |
| I <sub>DD</sub>                                                |           | 1                                    | μA max  | V <sub>DD</sub> = 5.5 V                                                                               |
|                                                                | 0.001     |                                      | μA typ  | Digital inputs = 0 V or V <sub>DD</sub>                                                               |

<sup>1</sup> Temperature range for B version is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

<sup>2</sup> Guaranteed by design, not subject to production test.

# ADG774A

$V_{DD} = 3\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , all specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.<sup>1</sup>

**Table 2.**

| Parameter                                                | B Version |                                      | Unit    | Test Conditions/Comments                                                                                |
|----------------------------------------------------------|-----------|--------------------------------------|---------|---------------------------------------------------------------------------------------------------------|
|                                                          | 25°C      | T <sub>MIN</sub> to T <sub>MAX</sub> |         |                                                                                                         |
| ANALOG SWITCH                                            |           |                                      |         |                                                                                                         |
| Analog Signal Range                                      |           | 0 to 1.5                             | V       |                                                                                                         |
| On Resistance, R <sub>ON</sub>                           | 4         |                                      | Ω typ   | V <sub>D</sub> = 0 V to 1 V; I <sub>S</sub> = −10 mA                                                    |
|                                                          | 6         | 7                                    | Ω max   |                                                                                                         |
| On Resistance Match Between Channels, ΔR <sub>ON</sub>   | 0.15      |                                      | Ω typ   | V <sub>D</sub> = 0 V to 1 V, I <sub>S</sub> = −10 mA                                                    |
|                                                          |           | 0.5                                  | Ω max   |                                                                                                         |
| On Resistance Flatness, R <sub>FLAT(ON)</sub>            | 1.5       |                                      | Ω typ   | V <sub>D</sub> = 0 V to 1 V, I <sub>S</sub> = −10 mA                                                    |
|                                                          |           | 3                                    | Ω max   |                                                                                                         |
| LEAKAGE CURRENTS                                         |           |                                      |         |                                                                                                         |
| Source Off Leakage, I <sub>S</sub> (OFF)                 | ±0.001    |                                      | nA typ  | V <sub>D</sub> = 2 V/1 V, V <sub>S</sub> = 1 V/2 V, see Figure 17                                       |
|                                                          | ±0.1      | ±0.25                                | nA max  |                                                                                                         |
| Drain Off Leakage, I <sub>D</sub> (OFF)                  | ±0.001    |                                      | nA typ  | V <sub>D</sub> = 2 V/1 V, V <sub>S</sub> = 1 V/2 V, see Figure 17                                       |
|                                                          | ±0.1      | ±0.25                                | nA max  |                                                                                                         |
| Channel On Leakage, I <sub>D</sub> , I <sub>S</sub> (ON) | ±0.001    |                                      | nA typ  | V <sub>D</sub> = V <sub>S</sub> = 2 V/1 V, see Figure 18                                                |
|                                                          | ±0.1      | ±0.25                                | nA max  |                                                                                                         |
| DIGITAL INPUTS                                           |           |                                      |         |                                                                                                         |
| Input High Voltage, V <sub>INH</sub>                     |           | 2.0                                  | V min   |                                                                                                         |
| Input Low Voltage, V <sub>INL</sub>                      |           | 0.4                                  | V max   |                                                                                                         |
| Input Current                                            |           |                                      |         |                                                                                                         |
| I <sub>INL</sub> or I <sub>INH</sub>                     | 0.001     |                                      | μA typ  | V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>                                                  |
|                                                          |           | ±0.1                                 | μA max  |                                                                                                         |
| Digital Input Capacitance, C <sub>IN</sub>               |           | 3                                    | pF typ  |                                                                                                         |
| DYNAMIC CHARACTERISTICS <sup>2</sup>                     |           |                                      |         |                                                                                                         |
| t <sub>ON</sub> , t <sub>ON</sub> (EN)                   |           | 7                                    | ns typ  | C <sub>L</sub> = 35 pF, R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 1.5 V, see Figure 22                    |
|                                                          |           | 14                                   | ns max  |                                                                                                         |
| t <sub>OFF</sub> , t <sub>OFF</sub> (EN)                 |           | 4                                    | ns typ  | C <sub>L</sub> = 35 pF, R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 1.5 V, see Figure 22                    |
|                                                          |           | 8                                    | ns max  |                                                                                                         |
| Break-Before-Make Time Delay, t <sub>D</sub>             |           | 3                                    | ns typ  | C <sub>L</sub> = 35 pF, R <sub>L</sub> = 50 Ω, V <sub>S1</sub> = V <sub>S2</sub> = 1.5 V, see Figure 23 |
|                                                          |           | 1                                    | ns min  |                                                                                                         |
| Off Isolation                                            |           | −65                                  | dB typ  | f = 10 MHz, R <sub>L</sub> = 50 Ω                                                                       |
| Channel-to-Channel Crosstalk                             |           | −70                                  | dB typ  | f = 10 MHz, R <sub>L</sub> = 50 Ω, see Figure 21                                                        |
| Bandwidth −3 dB                                          |           | 400                                  | MHz typ | R <sub>L</sub> = 50 Ω, see Figure 19                                                                    |
| Distortion                                               |           | 1.5                                  | % typ   | R <sub>L</sub> = 100 Ω                                                                                  |
| Charge Injection                                         |           | 4                                    | pC typ  | C <sub>L</sub> = 1 nF, see Figure 24, V <sub>S</sub> = 0 V                                              |
| C <sub>S</sub> (OFF)                                     |           | 5                                    | pF typ  |                                                                                                         |
| C <sub>D</sub> (OFF)                                     |           | 7.5                                  | pF typ  |                                                                                                         |
| C <sub>D</sub> , C <sub>S</sub> (ON)                     |           | 12                                   | pF typ  |                                                                                                         |
| POWER REQUIREMENTS                                       |           |                                      |         |                                                                                                         |
| I <sub>DD</sub>                                          |           | 1                                    | μA max  | V <sub>DD</sub> = 3.3 V                                                                                 |
|                                                          | 0.001     |                                      | μA typ  | Digital inputs = 0 V or V <sub>DD</sub>                                                                 |

<sup>1</sup> Temperature range for B version is  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ .

<sup>2</sup> Guaranteed by design, not subject to production test.

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 3.**

| Parameters                          | Rating                                                      |
|-------------------------------------|-------------------------------------------------------------|
| $V_{DD}$ to GND                     | –0.3 V to +6 V                                              |
| Analog, Digital Inputs <sup>1</sup> | –0.3 V to $V_{DD} + 0.3$ V or 30 mA, whichever occurs first |
| Continuous Current, S or D          | 100 mA                                                      |
| Peak Current, S or D                | 300 mA (pulsed at 1 ms, 10% duty cycle max)                 |
| Operating Temperature Range         |                                                             |
| Industrial (B Version)              | –40°C to +85°C                                              |
| Storage Temperature Range           | –65°C to +150°C                                             |
| Junction Temperature                | 150°C                                                       |
| Thermal Impedance, $\theta_{JA}$    |                                                             |
| 16-Lead QSSOP                       | 105.44°C/W <sup>2</sup>                                     |
| 16-Lead LFCSP(3 mm × 3 mm)          | 48.7°C/W <sup>2</sup>                                       |
| Lead Temperature Soldering          |                                                             |
| Vapor Phase (60 sec)                | 215°C                                                       |
| Infrared (15 sec)                   | 220°C                                                       |
| Reflow Soldering (Pb-free)          |                                                             |
| Peak Temperature                    | 260°C (+0°C/–5°C)                                           |
| Time at Peak Temperature            | 10 sec to 40 sec                                            |

<sup>1</sup> Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

<sup>2</sup> Measured with the device soldered on a four-layer board.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

### ESD CAUTION



#### **ESD (electrostatic discharge) sensitive device.**

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# ADG774A

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

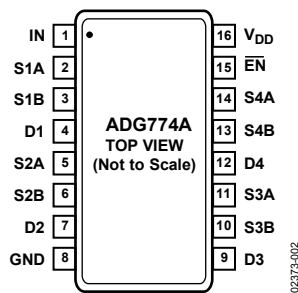
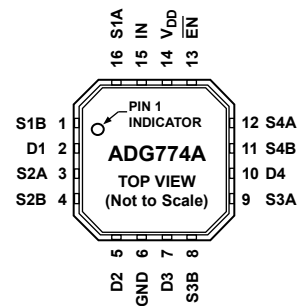


Figure 2. QSOP Pin Configuration



NOTES  
1. THE EXPOSED PAD SHOULD BE TIED TO GND.

Figure 3. LFCSP Pin Configuration

Table 4. Pin Function Descriptions

| Pin No. |       | Mnemonic | Function                                                   |
|---------|-------|----------|------------------------------------------------------------|
| QSOP    | LFCSP |          |                                                            |
| 1       | 15    | IN       | Logic Control Input.                                       |
| 2       | 16    | S1A      | Source Terminal 1A. May be an input or output.             |
| 3       | 1     | S1B      | Source Terminal 1B. May be an input or output.             |
| 4       | 2     | D1       | Drain Terminal D1. May be an input or output.              |
| 5       | 3     | S2A      | Source Terminal 2A. May be an input or output.             |
| 6       | 4     | S2B      | Source Terminal 2B. May be an input or output.             |
| 7       | 5     | D2       | Drain Terminal D2. May be an input or output.              |
| 8       | 6     | GND      | Ground (0 V) Reference.                                    |
| 9       | 7     | D3       | Drain Terminal D3. May be an input or output.              |
| 10      | 8     | S3B      | Source Terminal 3B. May be an input or output.             |
| 11      | 9     | S3A      | Source Terminal 3A. May be an input or output.             |
| 12      | 10    | D4       | Drain Terminal D4. May be an input or output.              |
| 13      | 11    | S4B      | Source Terminal 4B. May be an input or output.             |
| 14      | 12    | S4A      | Source Terminal 4A. May be an input or output.             |
| 15      | 13    | EN       | Logic Control Input. When high, all switches are disabled. |
| 16      | 14    | VDD      | Most Positive Power Supply Potential.                      |

Table 5. Truth Table

| EN | IN | D1   | D2   | D3   | D4   | Function |
|----|----|------|------|------|------|----------|
| 1  | X  | Hi-Z | Hi-Z | Hi-Z | Hi-Z | DISABLE  |
| 0  | 0  | S1A  | S2A  | S3A  | S4A  | IN = 0   |
| 0  | 1  | S1B  | S2B  | S3B  | S4B  | IN = 1   |

## TYPICAL PERFORMANCE CHARACTERISTICS

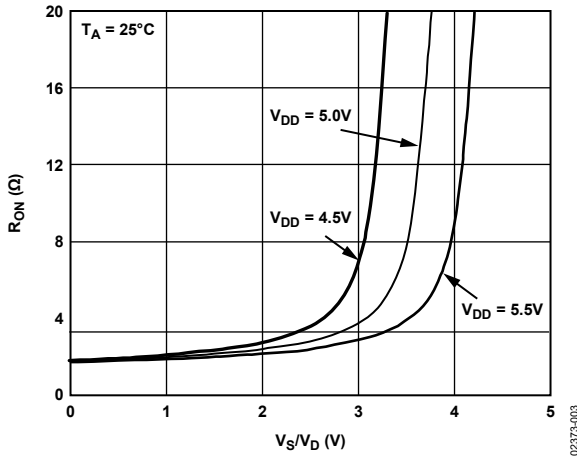


Figure 4. On Resistance as a Function of Drain ( $V_D$ ) or Source ( $V_S$ ) Voltage for  $V_{DD} = 5\text{ V} \pm 10\%$

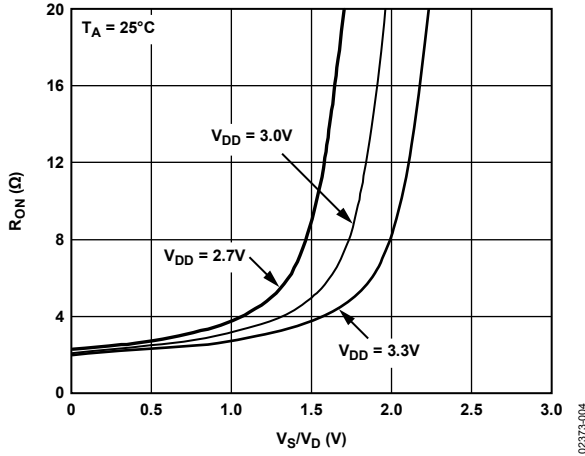


Figure 5. On Resistance as a Function of Drain ( $V_D$ ) or Source ( $V_S$ ) Voltage for  $V_{DD} = 3\text{ V} \pm 10\%$

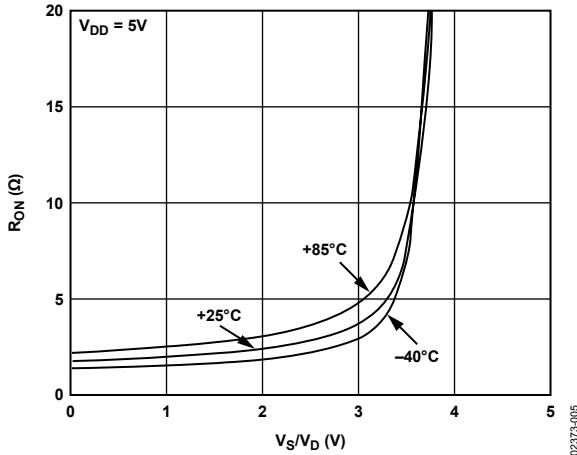


Figure 6. On Resistance as a Function of Drain ( $V_D$ ) or Source ( $V_S$ ) Voltage for Different Temperatures with 5 V Single Supplies

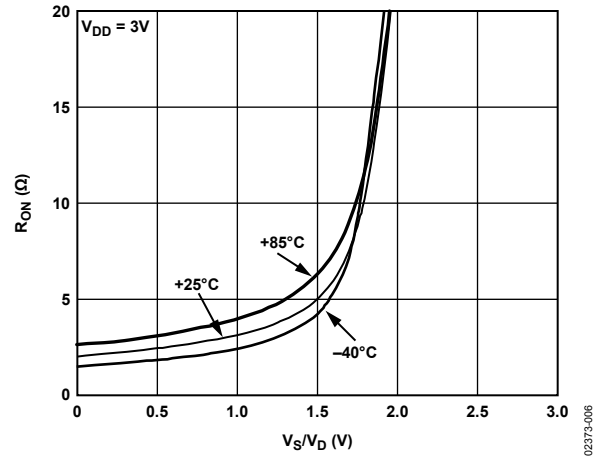


Figure 7. On Resistance as a Function of Drain ( $V_D$ ) or Source ( $V_S$ ) Voltage for Different Temperatures with 3 V Single Supplies

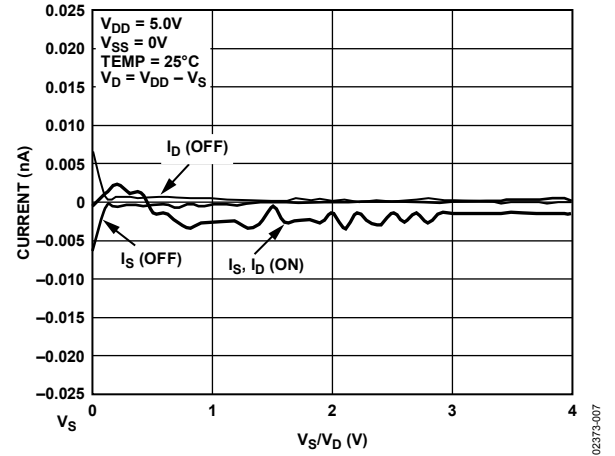


Figure 8. Leakage Current as a Function of Drain ( $V_D$ ) or Source ( $V_S$ ) Voltage for  $V_{DD} = 5\text{ V}$

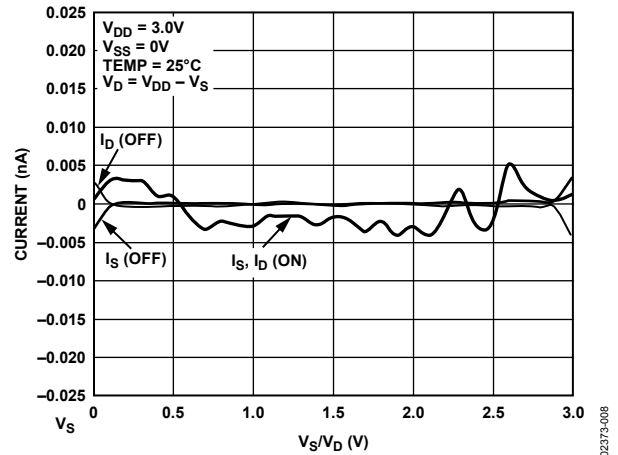


Figure 9. Leakage Current as a Function of Drain ( $V_D$ ) or Source ( $V_S$ ) Voltage for  $V_{DD} = 3\text{ V}$

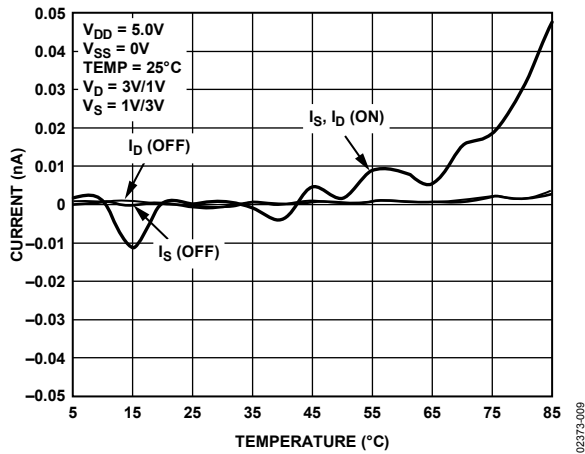


Figure 10. Leakage Current as a Function of Temperature,  $V_{DD} = 5 V$

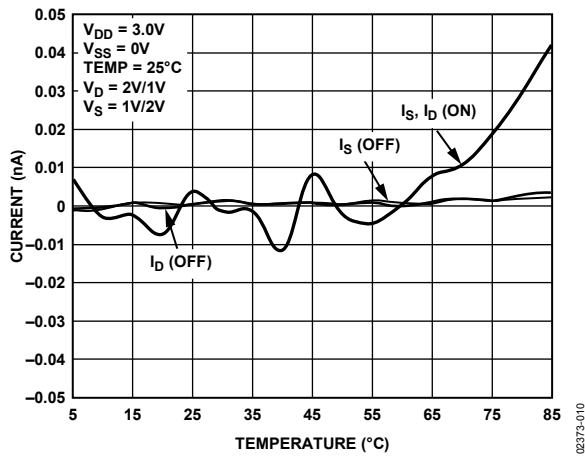


Figure 11. Leakage Current as a Function of Temperature,  $V_{DD} = 3 V$

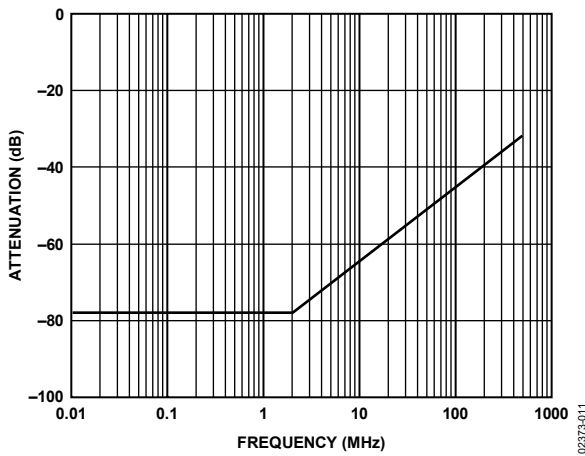


Figure 12. Off Isolation vs. Frequency

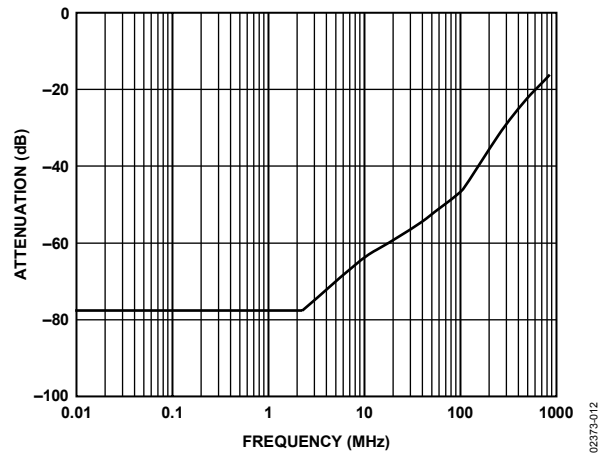


Figure 13. Crosstalk vs. Frequency

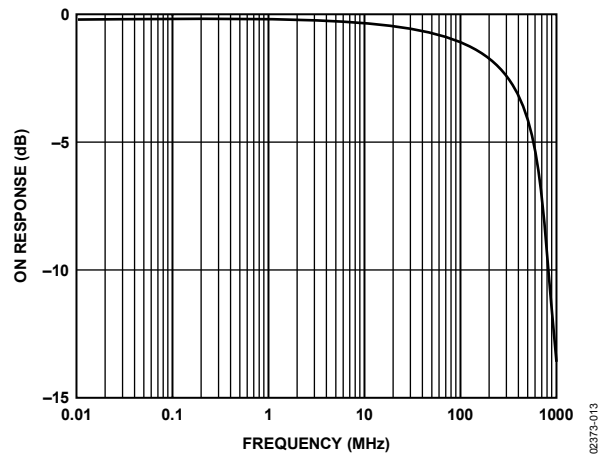


Figure 14. Bandwidth

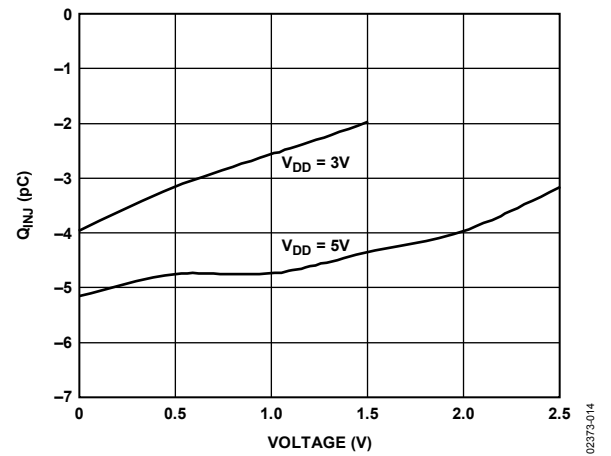


Figure 15. Charge Injection vs. Source Voltage



## TEST CIRCUITS

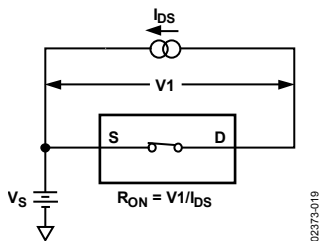


Figure 16. On Resistance

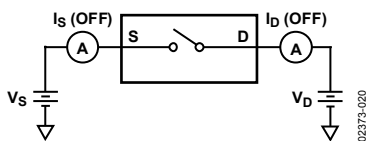


Figure 17. Off Leakage

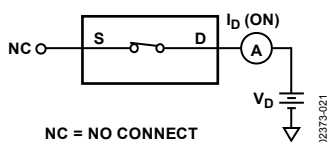


Figure 18. On Leakage

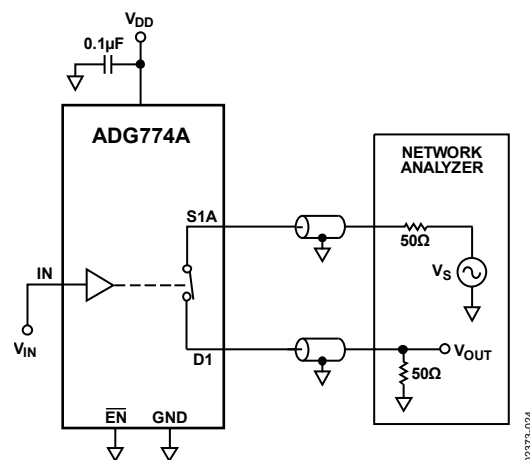


Figure 19. Bandwidth

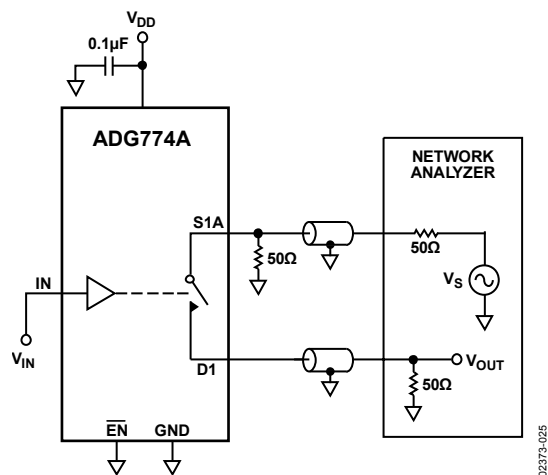


Figure 20. Off Isolation

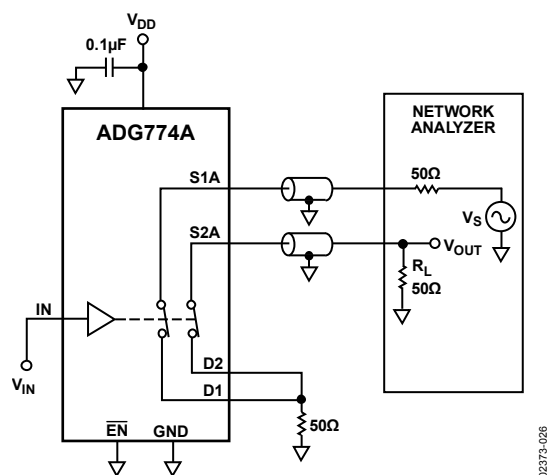


Figure 21. Channel-to-Channel Crosstalk

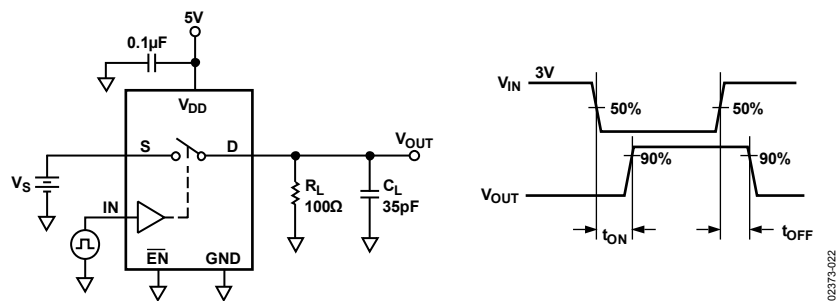


Figure 22. Switching Times

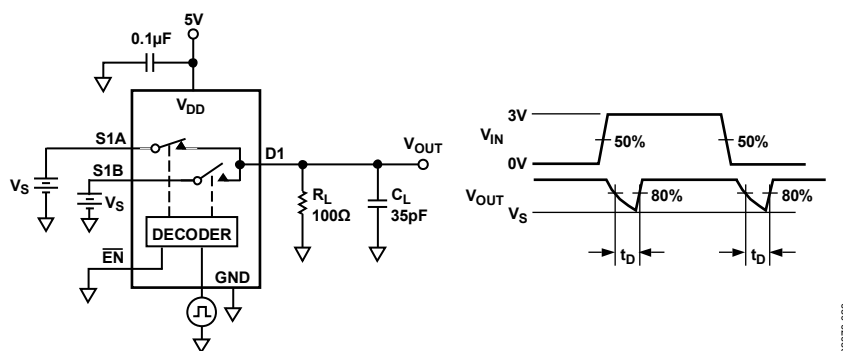


Figure 23. Break-Before-Make Time Delay

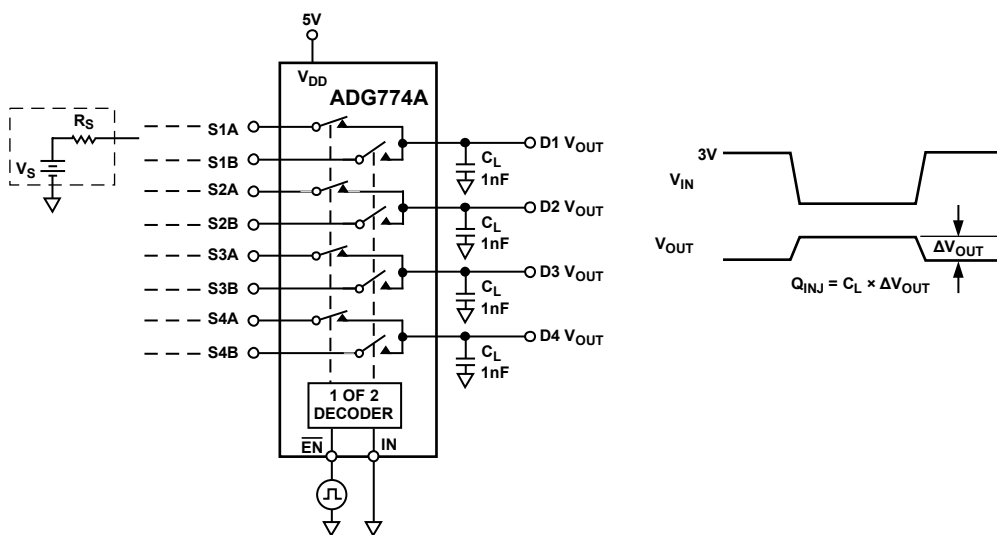


Figure 24. Charge Injection

## TERMINOLOGY

### $V_{DD}$

Most positive power supply potential.

### GND

Ground (0 V) reference.

### S

Source terminal. May be an input or output.

### D

Drain terminal. May be an input or output.

### IN

Logic control input.

### $\overline{\text{EN}}$

Logic control input.

### $R_{ON}$

Ohmic resistance between D and S.

### $\Delta R_{ON}$

On resistance match between any two channels, that is,  $R_{ON \text{ max}} - R_{ON \text{ min}}$ .

### $R_{\text{FLAT(ON)}}$

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

### $I_S$ (OFF)

Source leakage current with the switch off.

### $I_D$ (OFF)

Drain leakage current with the switch off.

### $I_D, I_S$ (ON)

Channel leakage current with the switch on.

### $V_D$ ( $V_S$ )

Analog voltage on the D and S terminals.

### $C_S$ (OFF)

Off switch source capacitance.

### $C_D$ (OFF)

Off switch drain capacitance.

### $C_D, C_S$ (ON)

On switch capacitance.

### $t_{ON}$

Delay between applying the digital control input and the output switching on. See Figure 22.

### $t_{OFF}$

Delay between applying the digital control input and the output switching off.

### $t_D$

Off time or on time measured between the 80% points of both switches when switching from one address state to another. See Figure 23.

### Crosstalk

A measure of unwanted signal that is coupled through from one channel to another because of parasitic capacitance.

### Off Isolation

A measure of unwanted signal coupling through an off switch.

### Bandwidth

Frequency response of the switch in the on state measured at 3 dB down.

### Distortion

$R_{\text{FLAT(ON)}}/R_L$

APPLICATION CIRCUITS

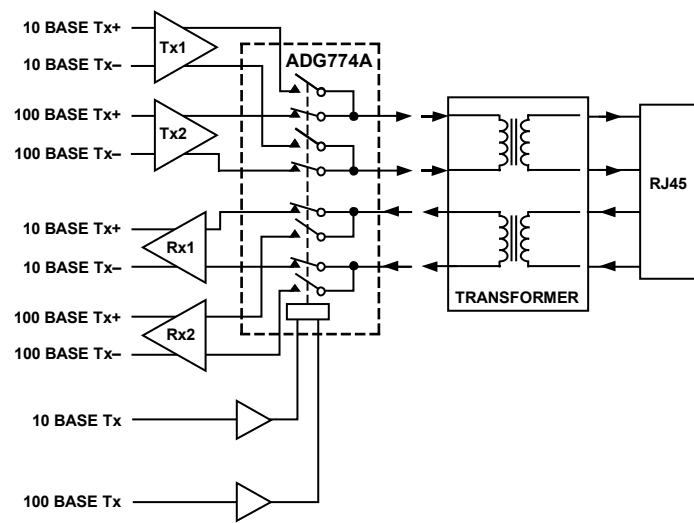


Figure 25. Full Duplex Transceiver

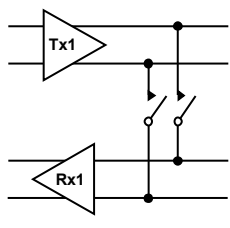


Figure 26. Loop Back

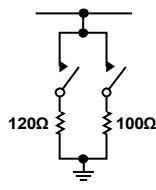


Figure 27. Line Termination

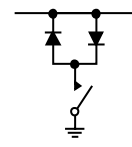
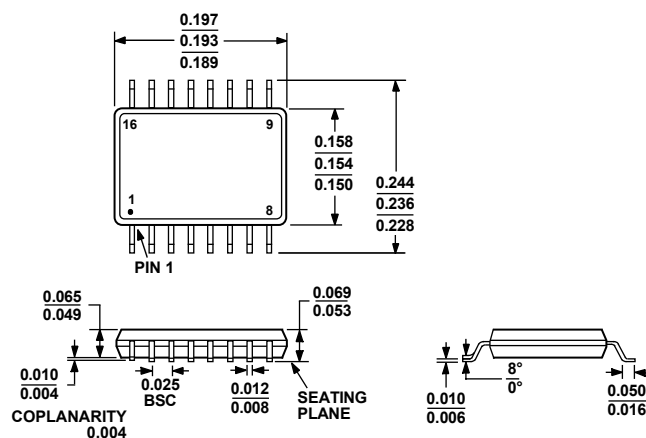


Figure 28. Line Clamp

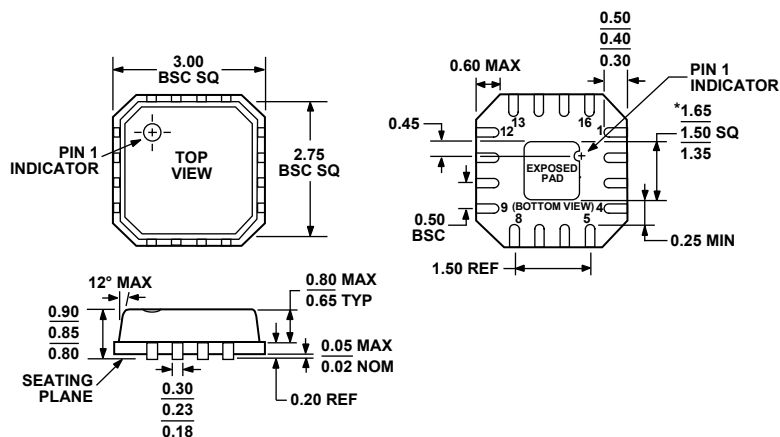
## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-137-AB

Figure 29. 16-Lead Shrink Small Outline Package [QSOP]  
(RQ-16)

Dimensions shown in inches



\*COMPLIANT TO JEDEC STANDARDS MO-220-VEED-2  
EXCEPT FOR EXPOSED PAD DIMENSION.

Figure 30. 16-Lead Lead Frame Chip Scale Package [LFCSP\_VQ]  
(CP-16-3)

Dimensions shown in millimeters

## ORDERING GUIDE

| Model                          | Temperature Range | Package Description                              | Package Option |
|--------------------------------|-------------------|--------------------------------------------------|----------------|
| ADG774ABRQ                     | -40°C to +85°C    | 16-Lead Shrink Small Outline Package [QSOP]      | RQ-16          |
| ADG774ABRQ-REEL                | -40°C to +85°C    | 16-Lead Shrink Small Outline Package [QSOP]      | RQ-16          |
| ADG774ABRQ-REEL7               | -40°C to +85°C    | 16-Lead Shrink Small Outline Package [QSOP]      | RQ-16          |
| ADG774ABRQZ <sup>1</sup>       | -40°C to +85°C    | 16-Lead Shrink Small Outline Package [QSOP]      | RQ-16          |
| ADG774ABRQZ-REEL <sup>1</sup>  | -40°C to +85°C    | 16-Lead Shrink Small Outline Package [QSOP]      | RQ-16          |
| ADG774ABRQZ-REEL7 <sup>1</sup> | -40°C to +85°C    | 16-Lead Shrink Small Outline Package [QSOP]      | RQ-16          |
| ADG774ABCPZ-REEL               | -40°C to +85°C    | 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ] | CP-16-3        |

<sup>1</sup> Z = Pb-free part.

**ADG774A**

**NOTES**

**NOTES**

**ADG774A**

**NOTES**



Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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